

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

MDP1921

FEATURES

- · With low gate drive requirements
- · Easy to drive
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

- Switching applications
- For DC-DC converter

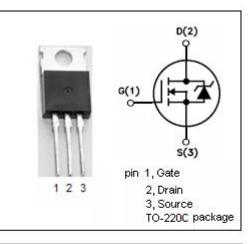
• ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

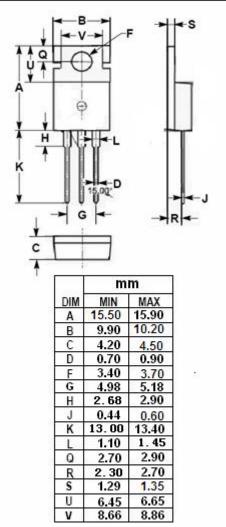
SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	100	V	
V _{GSS}	Gate-Source Voltage	±20	V	
ID	Drain Current-Continuous@Tc=25℃ Tc=100℃	153 97	A	
I _{DM}	Drain Current-Single Pulsed	480	А	
PD	Total Dissipation @T _c =25℃ T _c =100℃	223 89	W	
Tj	Operating Junction Temperature	-55~150	°C	
T _{stg}	Storage Temperature	-55~150	°C	

• THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	0.56	°C/W	
Rth(ch-a)	Channel-to-ambient thermal resistance	62.5	°C/W	

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ELECTRICAL CHARACTERISTICS

$T_{C}\text{=}25^{\circ}\!\!\!\mathrm{C}$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	100			V
V _{GS} (th)	Gate Threshold Voltage	V _{DS} =±20V; I _D =0.25mA	2		4	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =50A		3.9	4.5	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} =0V			±0.1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 80V; V _{GS} = 0V			1	μA
V _{SDF}	Diode forward voltage	I _{SD} =50A, V _{GS} = 0 V			1.2	V

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